

# **TDA7372A**

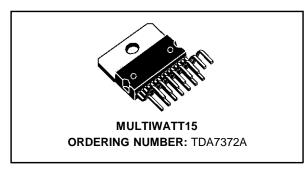
# 4 x 6W POWER AMPLIFIER FOR CAR RADIO

**ADVANCE DATA** 

- HIGH POWER CAPABILITY: 4x6W min/4Ω @14.4V, 1KHz, 10% 4x10W typ/2Ω @14.4V, 1KHz, 10%
- MINIMUM EXTERNAL COMPONENT COUNT
  - INTERNALLY FIXED GAIN (20dB)
  - NO BOOTSTRAP CAPACITORS
  - NO EXTERNAL COMPENSATION
- ST-BY FUNCTION (CMOS COMPATIBLE)
- MUTE FUNCTION (CMOS COMPATIBLE)
- NO AUDIBLE POP DURING MUTE/ST-BY OPERATIONS
- LOW SUPPLY SELF MUTING
- PROGRAMMABLE TURN ON DELAY

#### PROTECTIONS:

- AC OUTPUT SHORT CIRCUIT TO GND
- DC OUTPUT SHORT CIRCUIT TO GND AND TO V<sub>S</sub> AT POWER ON
- SOFT THERMAL LIMITER
- OVERRATING CHIP TEMPERATURE
- LOAD DUMP VOLTAGE



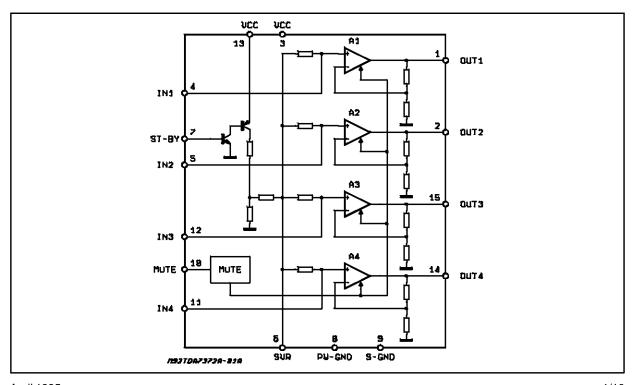
- FORTUITOUS OPEN GND
- REVERSED BATTERY
- ESD PROTECTION

#### **DESCRIPTION**

The TDA7372A is a new technology class AB quad channels Audio Power Amplifier in Multiwatt15 package designed for car radio applications.

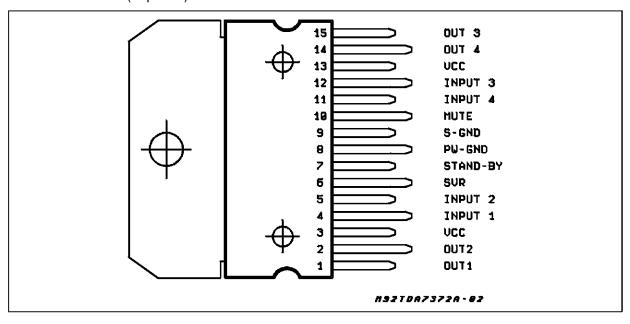
Thanks to the fully complementary PNP/NPN output configuration the TDA7372A delivers a rail to rail voltage swing with no need of boostrap capacitors.

#### **BLOCK DIAGRAM**



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## **PIN CONNECTION** (Top view)



#### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
Vs	DC Supply Voltage	28	V
V <sub>OP</sub>	Operating Supply Voltage	18	V
$V_{PEAK}$	Peak Supply Voltage (t = 50ms)	50	V
lo	Output Peak Current (not rep. t = 100μs)	4	Α
lo	Output Peak Current (rep. f > 10Hz)	3	Α
P <sub>tot</sub>	Power Dissipation (T <sub>case</sub> = 85°C)	32	W
T <sub>stg</sub> , T <sub>j</sub>	Storage and Junction Temperature	-40 to 150	°C

#### THERMAL DATA

Symbol	Description		Value	Unit
R <sub>th j-case</sub>	Thermal Resistance Junction-case	Max	2	°C/W

# **ELECTRICAL CHARACTERISTICS** (Refer to the test circuit; $V_S$ = 14.4V; $R_L$ = 4 $\Omega$ , $T_{amb}$ = 25°C, f = 1kHz, unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Unit
Vs	Supply Range		8		18	V
I <sub>d</sub>	Total Quiescent Drain Current				150	mA
Po	Output Power	$R_L = 4\Omega$ ; THD = 10% each channel	6	6.5		W
		$R_L = 2\Omega$ ; THD = 10% each channel		10		W
d	Distortion	$R_L = 4\Omega;$ $P_0 = 0.1 \text{ to } 3W$		0.04	0.3	%
СТ	Cross Talk	$f = 1kHz; R_g = 0$ $f = 10kHz; R_g = 0$	54	60 55		dB dB
R <sub>IN</sub>	Input Impedance		35			ΚΩ
G∨	Voltage Gain		19	20	21	dB
G∨	Voltage Gain Match.				1	dB
BW	Bandwidth	@ -3dB	100			KHz
E <sub>NO</sub>	Output Noise Voltage (*)	$R_g = 0$			120	μV
SVR	Supply Voltage Rejection	$R_g = 0$ ; $f = 100Hz$	48			dB
ASB	Stand-by Attenuation		80			dB
I <sub>SB</sub>	ST-BY Current Consumption	Vpin7 = 1.5V			100	μΑ
I <sub>PIN7</sub>	ST-BY Pin Current	Play mode; Vpin7 = 5V			30	μΑ
		Output Under Short (Max driving current under fault)			5	mA
V <sub>SB IN</sub>	ST-BY IN Threshold Voltage				1.5	V
V <sub>SB</sub> OUT	ST-BY OUT Threshold Voltage		3.5			V
A <sub>M</sub>	MUTE Attenuation			80		dB
$V_{M IN}$	MUTE IN Threshold Voltage				1.5	V
V <sub>м оит</sub>	MUTE OUT Threshold Voltage		3.5			V

<sup>(\*) 22</sup>Hz to 22KHz

#### **TEST AND APPLICATION CIRCUIT**

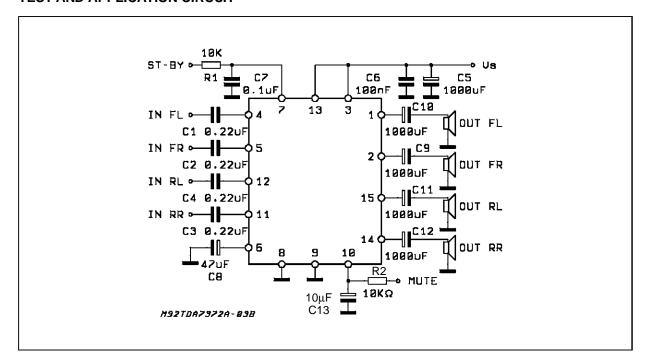


Figure 1: P.C. Board and components layout of the Test and Application Circuit (1:1 scale)

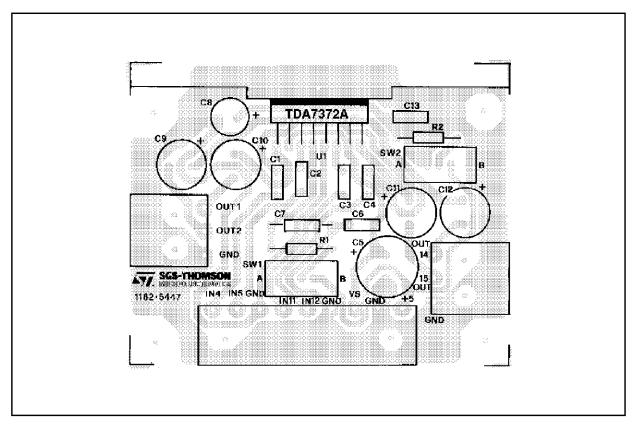


Figure 2: Quiescent Drain Current vs. Supply Voltage

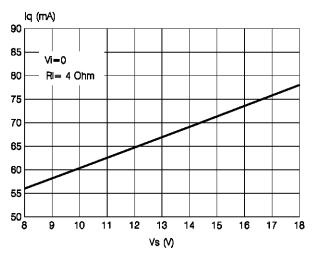


Figure 4: Output Power vs Supply Voltage

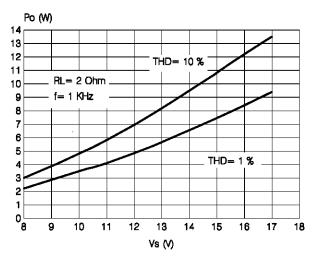


Figure 6: Distortion vs. Output Power

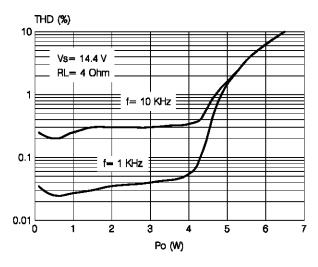
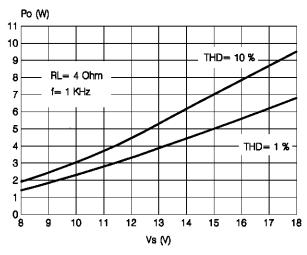


Figure 3: Output Power vs. Supply Voltage



**Figure 5:** Output power vs. Frequency vs.Cout Value

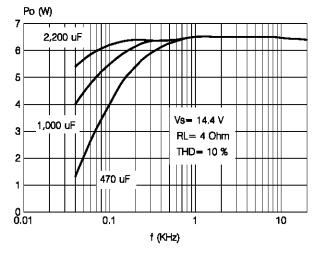


Figure 7: Distortion vs. Output Power

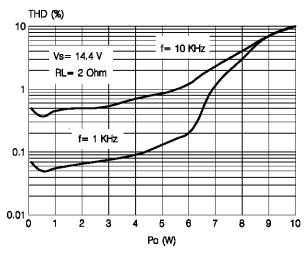


Figure 8: Distortion vs. Frequency

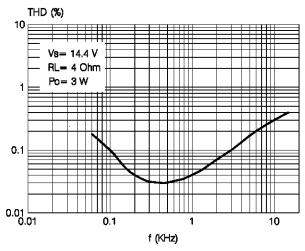
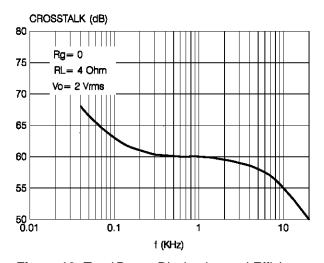


Figure 10: Cross-Talk vs. Frequency



**Figure 12:** Total Power Dissipation and Efficiency vs. Output Power

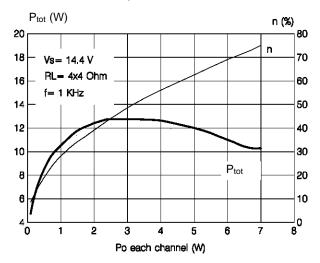


Figure 9: Distortion vs. Frequency

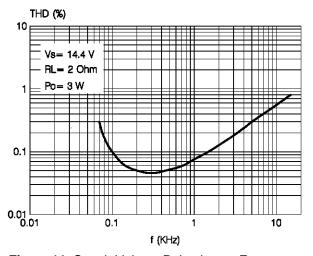
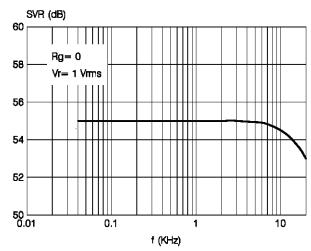
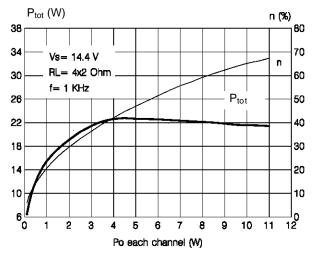


Figure 11: Supply Voltage Rejection vs. Frequency



**Figure 13:** Total Power Dissipation and Efficiency vs. Output Power



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Figure 14: TDA7313 + 7372 Application Circuit 10µF OUT4 18Ko OUTZ II OUT3 OUT1 180 \_\_\_\_\_1989∪F \_\_\_\_\_\_\_\_ Pu-GND 4 HH188nF H 47UF S ST-BY OFFICE ST-BY a.22uF IN1 Ø.22uF IN4 **■** 8.22∪F DIGGND SDA SCL 25 22 26 22 SPKR ATT SPKR SPKR SPKR BUS DECODER + LATCHES TREBLE 2.2uF 188nF 188nF 18 5.6K BASS BASS ₽₽ ₽ 🗍 D 립

SUPPLY

INPUTS

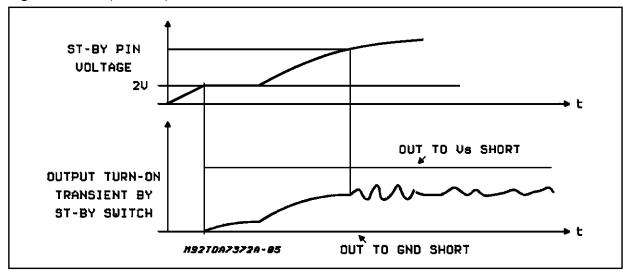
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INPUTS —

#### **FUNCTIONAL DESCRIPTION**

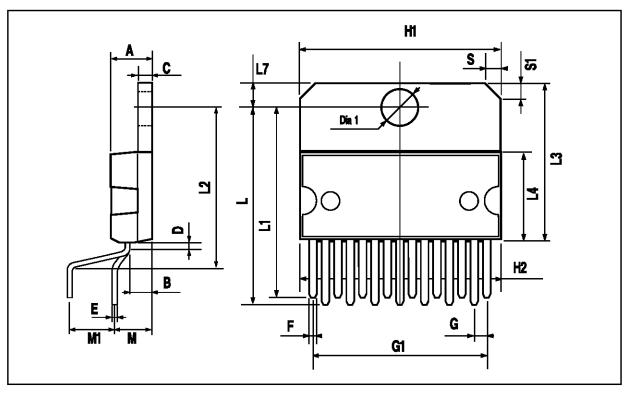
Function	Description
GENERAL	The TDA7372A is a quad channel single package audio power amplifier intended to reduce the mismatch in the electrical characteristics among the four different channels and to consistently drop the external component count. It contains four non inverting stages capable to operate down to 20dB gain so minimizing the output noise and optimizing SVR and distortion.
OUTPUT STAGE	The output stage is a single ended type suitable to drive $4\Omega$ loads. It consists of a class AB fully complementary PNP/NPN stages short circuit protected. A rail to rail output swing is achieved without need of boostrap capacitors. Moreover, the external compensation is not necessary.
ST-BY	The device features a St-BY function which shuts down the internal bias generators when the ST-BY input is low. In ST-BY mode the amplifier sinks a small current (in the range of few $\mu$ As). When the St-BY pin is high the IC becomes fully operational.
MUTE	A mute function is also provided. This reduces the gain of the input stage to a level effectively eliminating any audio input influence on the output stage when the mute line is low. When the mute line is high the normal input path is restored. The device goes automatically into mute state when the supply voltage goes below the minimum allowable value. This prevents pop noises whenever the battery voltage drops below a fixed threshold. When the supply voltage rises to it nominal value the device recovers the play condition with a delay fixed by the $C_{\text{SVR}}$ capacitor.
THERMAL PROTECTION	The Thermal protection principle involves two different steps a) Soft thermal limitation b) Shutdown As long as the junction temperature remains below a preset threshold, the I.C. will deliver the full power. Once the threshold has been reached, the device automatically goes into mute status. The play to mute transition is internally controlled so producing a soft muting without unpleasant effect. Supposing the junction temperature does not reduce to safe levels, a complete shutdown will occur.
BUILT-IN SHORT CIRCUIT PROTECTION	A built-in protection circuit assures reliable and safe operation in presence of: - AC short circuit to GND - DC short circuit to GND and to V <sub>S</sub> during power-on phase The DC short protector acts in a way to avoid that the device is being turned on (by ST-BY) when a DC short is present from OUT to GND or OUT to V <sub>S</sub> . Due to this reason it is necessary to introduce a proper delay on the st-by pin (expecially when it is driven by V <sub>S</sub> .) Moreover, as the involved circuitry is normally disabled when a current higher than 5mA is fed into the st-by pin, it is important, in order not to disable it, to have the external current source driving the pin itself limited to 5mA. (figure 1 is shows the relevant waveforms).

Figure 15: Fault (DC short) waveforms



## **MULTIWATT15 PACKAGE MECHANICAL DATA**

DIM.		mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
А			5			0.197	
В			2.65			0.104	
С			1.6			0.063	
D		1			0.039		
Е	0.49		0.55	0.019		0.022	
F	0.66		0.75	0.026		0.030	
G	1.14	1.27	1.4	0.045	0.050	0.055	
G1	17.57	17.78	17.91	0.692	0.700	0.705	
H1	19.6			0.772			
H2			20.2			0.795	
L	22.1		22.6	0.870		0.890	
L1	22		22.5	0.866		0.886	
L2	17.65		18.1	0.695		0.713	
L3	17.25	17.5	17.75	0.679	0.689	0.699	
L4	10.3	10.7	10.9	0.406	0.421	0.429	
L7	2.65		2.9	0.104		0.114	
М	4.2	4.3	4.6	0.165	0.169	0.181	
M1	4.5	5.08	5.3	0.177	0.200	0.209	
S	1.9		2.6	0.075		0.102	
S1	1.9		2.6	0.075		0.102	
Dia1	3.65		3.85	0.144		0.152	



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